

# DATA SHEET



## **BYD57 series** Ultra-fast soft-recovery controlled avalanche rectifiers

Product specification  
Supersedes data of 1998 Dec 04

1999 Nov 11

# Ultra-fast soft-recovery controlled avalanche rectifiers

## BYD57 series

### FEATURES

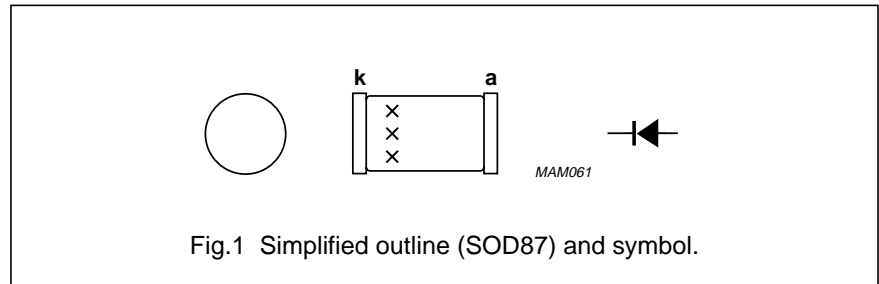
- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Shipped in 8 mm embossed tape
- Smallest surface mount rectifier outline.

### DESCRIPTION

Cavity free cylindrical glass SOD87 package through Implotec™(1) technology. The SOD87 is

hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

(1) Implotec is a trademark of Philips.



### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BYD57D		–	200	V
	BYD57G		–	400	V
	BYD57J		–	600	V
	BYD57K		–	800	V
	BYD57M		–	1000	V
	BYD57U BYD57V		–	1200 1400	V
V <sub>R</sub>	continuous reverse voltage				
	BYD57D		–	200	V
	BYD57G		–	400	V
	BYD57J		–	600	V
	BYD57K		–	800	V
	BYD57M		–	1000	V
	BYD57U BYD57V		–	1200 1400	V
I <sub>F(AV)</sub>	average forward current	T <sub>tp</sub> = 85 °C; see Figs 2 and 3; averaged over any 20 ms period; see also Figs 10 and 11			
	BYD57D to M BYD57U and V		–	1.0 1.2	A A
I <sub>F(AV)</sub>	average forward current	T <sub>amb</sub> = 60 °C; PCB mounting (see Fig.17); see Figs 4 and 5; averaged over any 20 ms period; see also Figs 10 and 11			
	BYD57D to M BYD57U and V		–	0.4 0.4	A A
I <sub>FRM</sub>	repetitive peak forward current	T <sub>tp</sub> = 85 °C; see Figs 6 and 7			
	BYD57D to M BYD57U and V		–	8.5 11	A A

## Ultra-fast soft-recovery controlled avalanche rectifiers

## BYD57 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{FRM}$	repetitive peak forward current	$T_{amb} = 60\text{ °C}$ ; see Figs 8 and 9	–	3.0	A
	BYD57D to M BYD57U and V			3.7	A
$I_{FSM}$	non-repetitive peak forward current	$t = 10\text{ ms}$ half sinewave; $T_j = 25\text{ °C}$ prior to surge; $V_R = V_{RRMmax}$	–	5.0	A
$E_{RSM}$	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$ ; $T_j = T_{jmax}$ prior to surge; inductive load switched off	–	10	mJ
$T_{stg}$	storage temperature		–65	+175	°C
$T_j$	junction temperature	see Fig.12	–65	+175	°C

### ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT				
$V_F$	forward voltage	$I_F = 1\text{ A}$ ; $T_j = T_{jmax}$ ; see Figs 13 and 14	–	–	2.1	V				
	BYD57D to M BYD57U and V				1.7	V				
$V_F$	forward voltage	$I_F = 1\text{ A}$ ; see Figs 13 and 14	–	–	3.6	V				
	BYD57D to M BYD57U and V				2.3	V				
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$								
	BYD57D						300	–	–	V
	BYD57G						500	–	–	V
	BYD57J						700	–	–	V
	BYD57K						900	–	–	V
	BYD57M						1100	–	–	V
	BYD57U BYD57V						1300 1500	–	–	V V
$I_R$	reverse current	$V_R = V_{RRMmax}$ ; see Fig.15	–	–	5	µA				
		$V_R = V_{RRMmax}$ ; $T_j = 165\text{ °C}$ ; see Fig.15	–	–	100	µA				
$t_{rr}$	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$ ; measured at $I_R = 0.25\text{ A}$ ; see Fig.18	–	–	30	ns				
	BYD57D to J				75	ns				
	BYD57K and M BYD57U and V				150	ns				
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 0$ ; see Fig.16	–	20	–	pF				

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## BYD57 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\left  \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1$ A to $V_R \geq 30$ V and $dI_F/dt = -1$ A/ $\mu$ s; see Fig.19	–	–	7	A/ $\mu$ s
	BYD57D to J					
	BYD57K and M					
	BYD57U and V		–	–	5	A/ $\mu$ s

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point		30	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	150	K/W

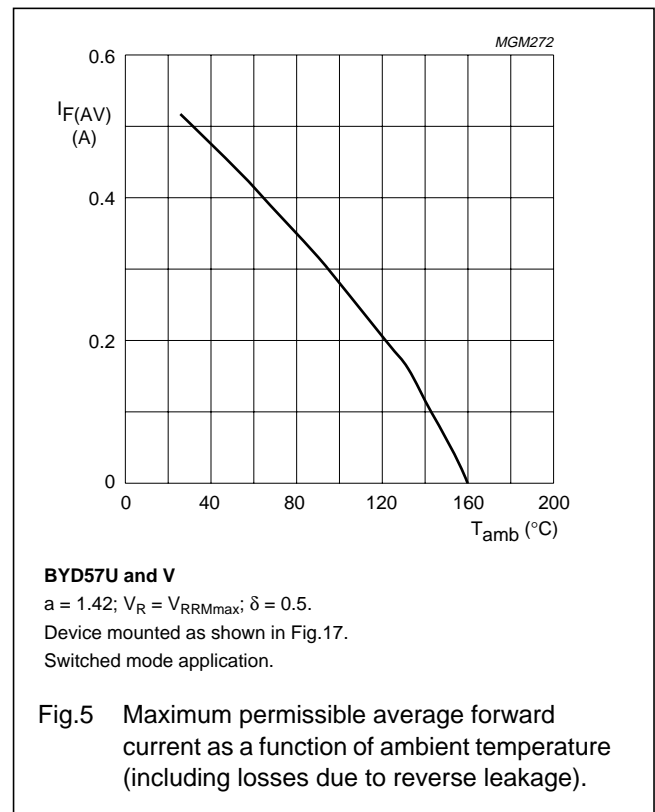
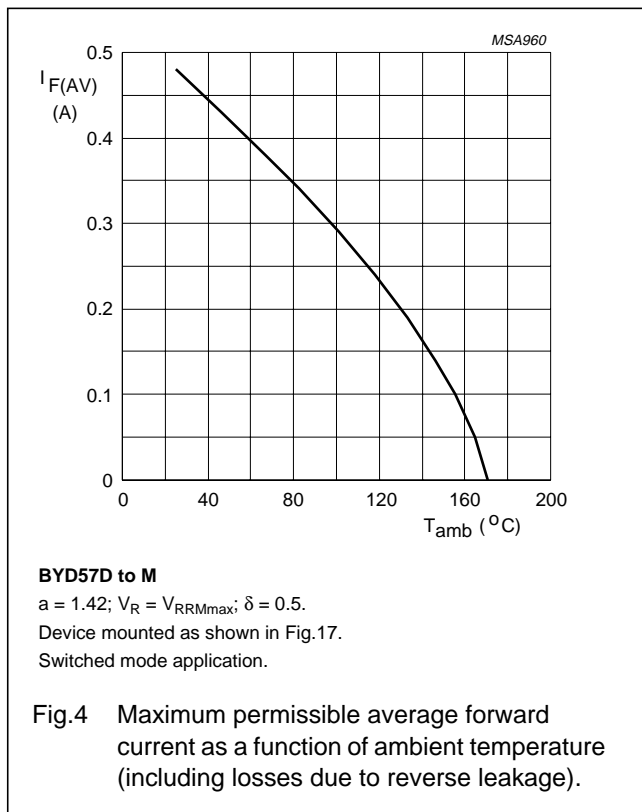
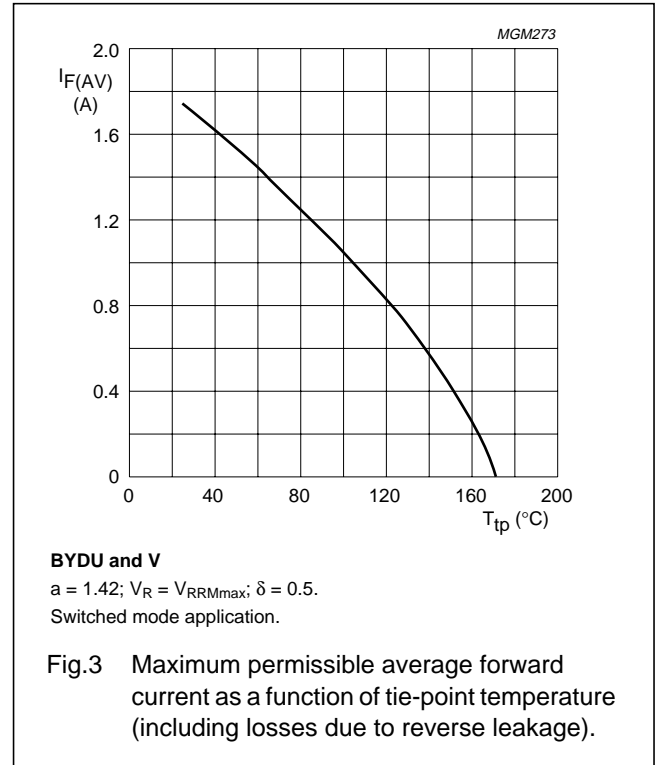
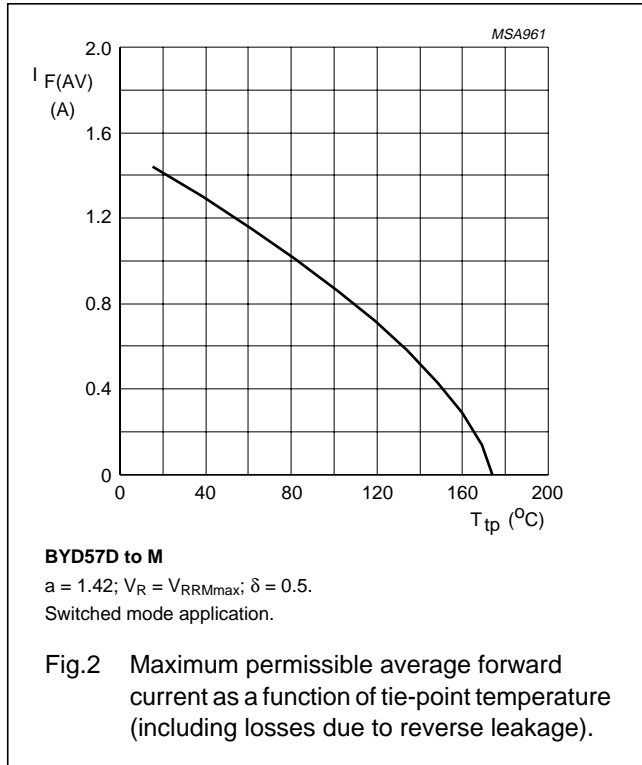
#### Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer  $\geq 40$   $\mu$ m, see Fig.17. For more information please refer to the 'General Part of associated Handbook'.

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controlled avalanche rectifiers

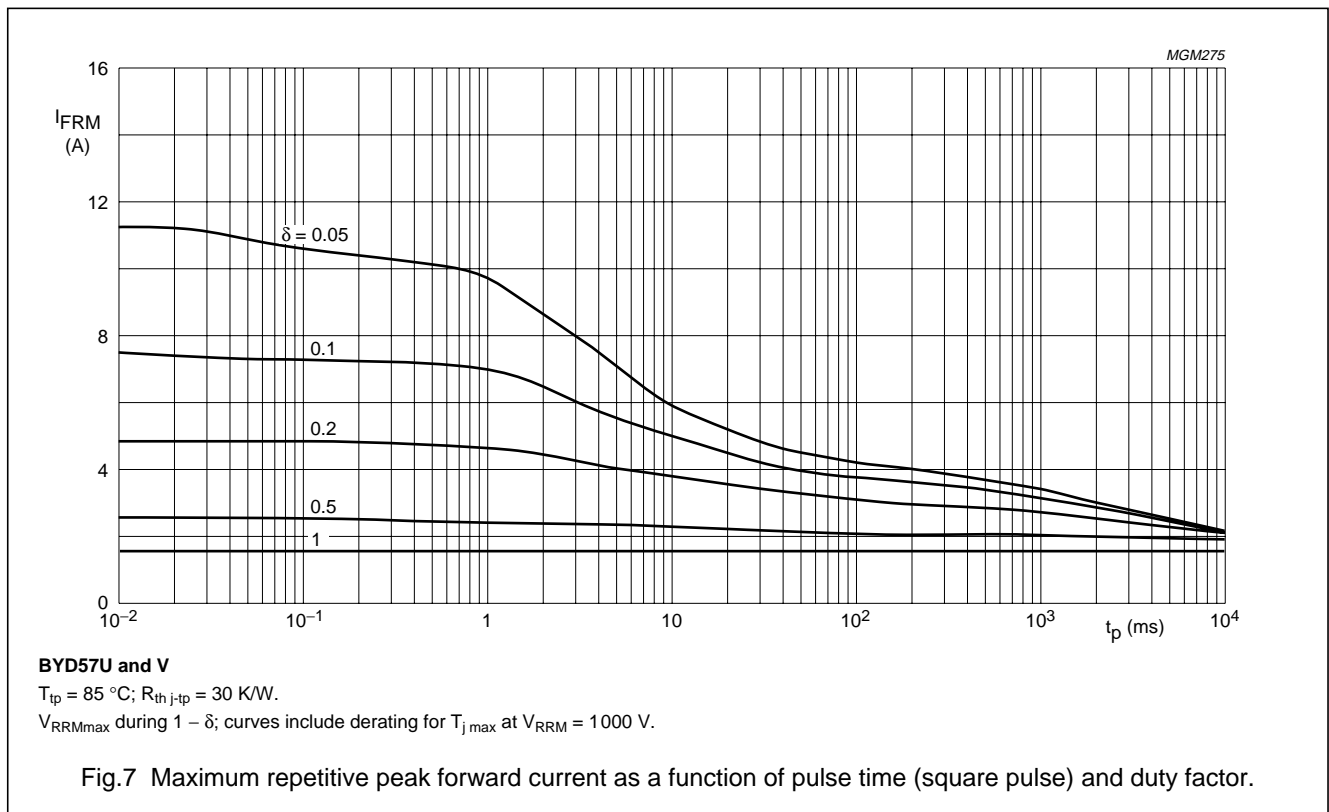
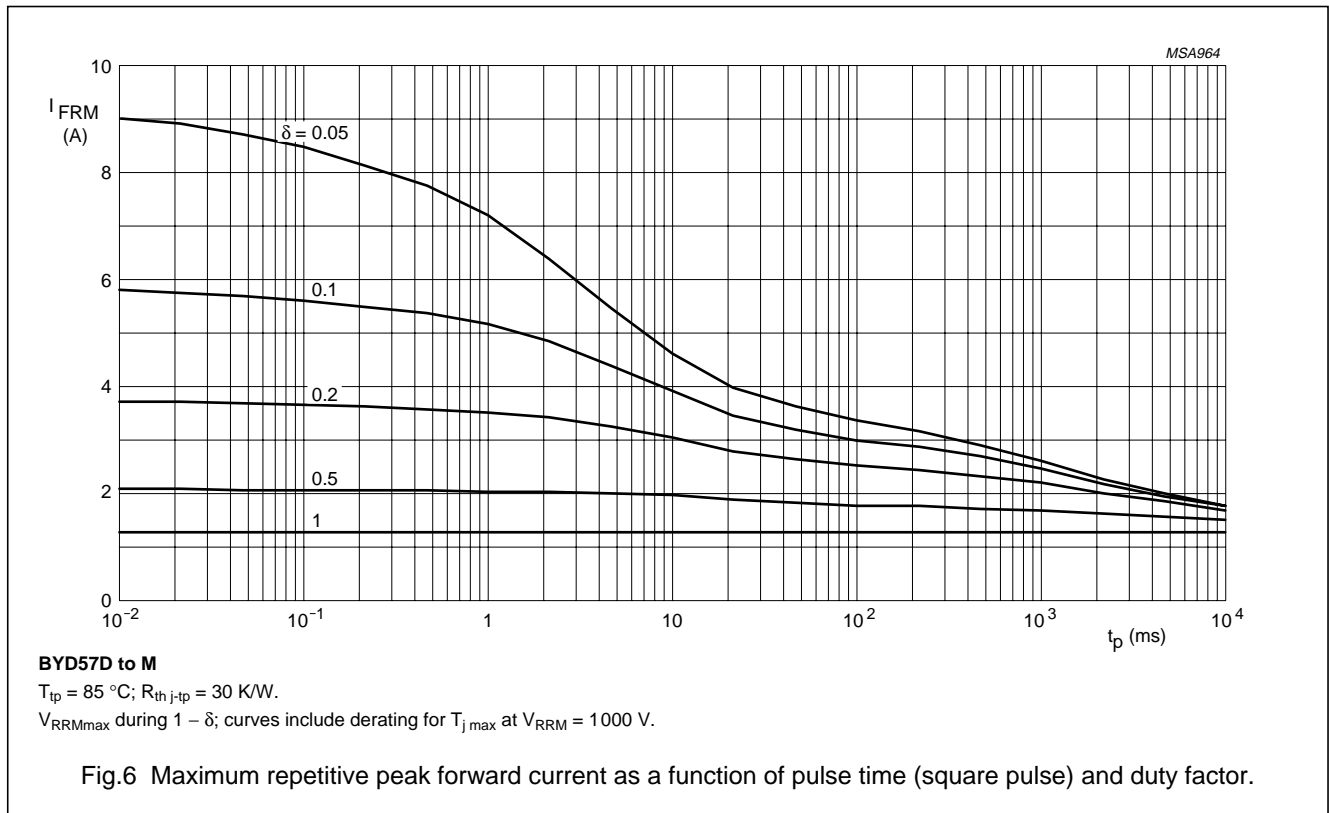
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GRAPHICAL DATA



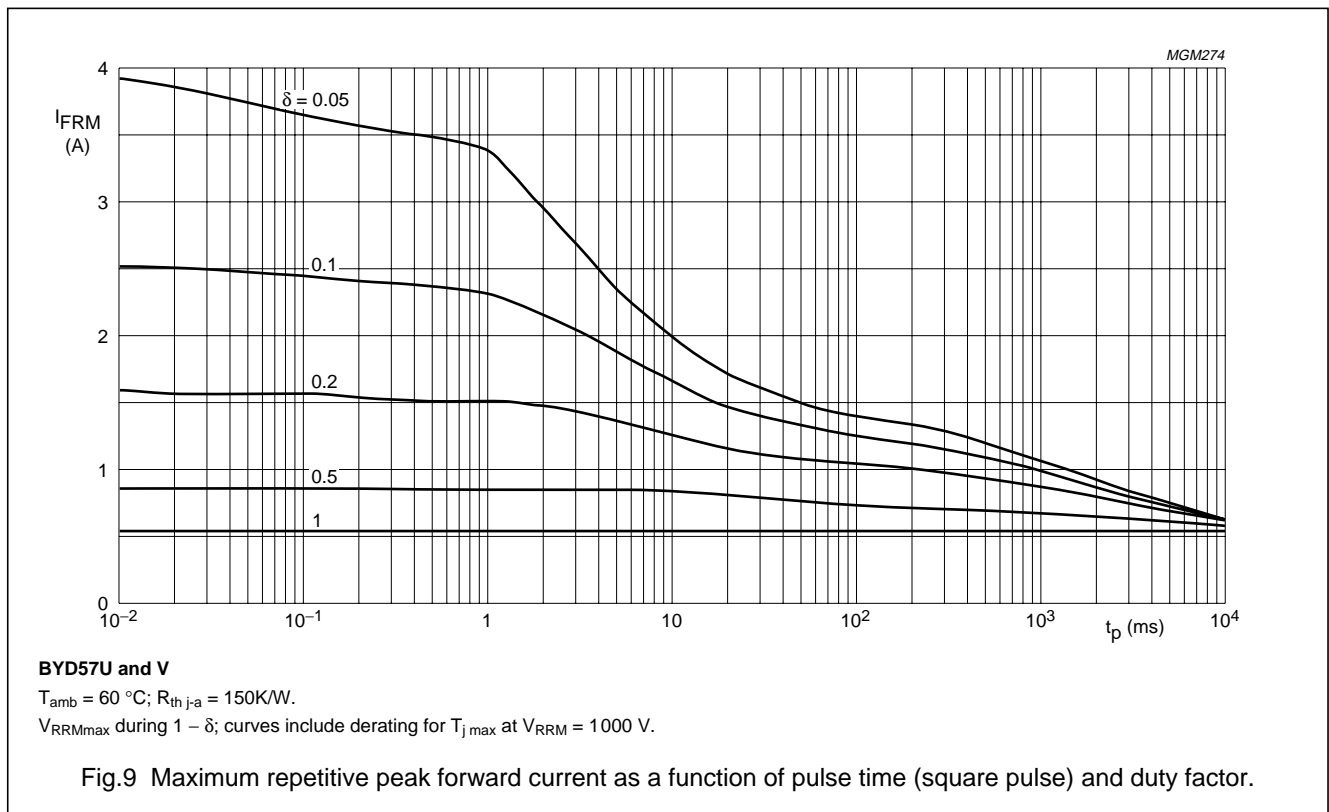
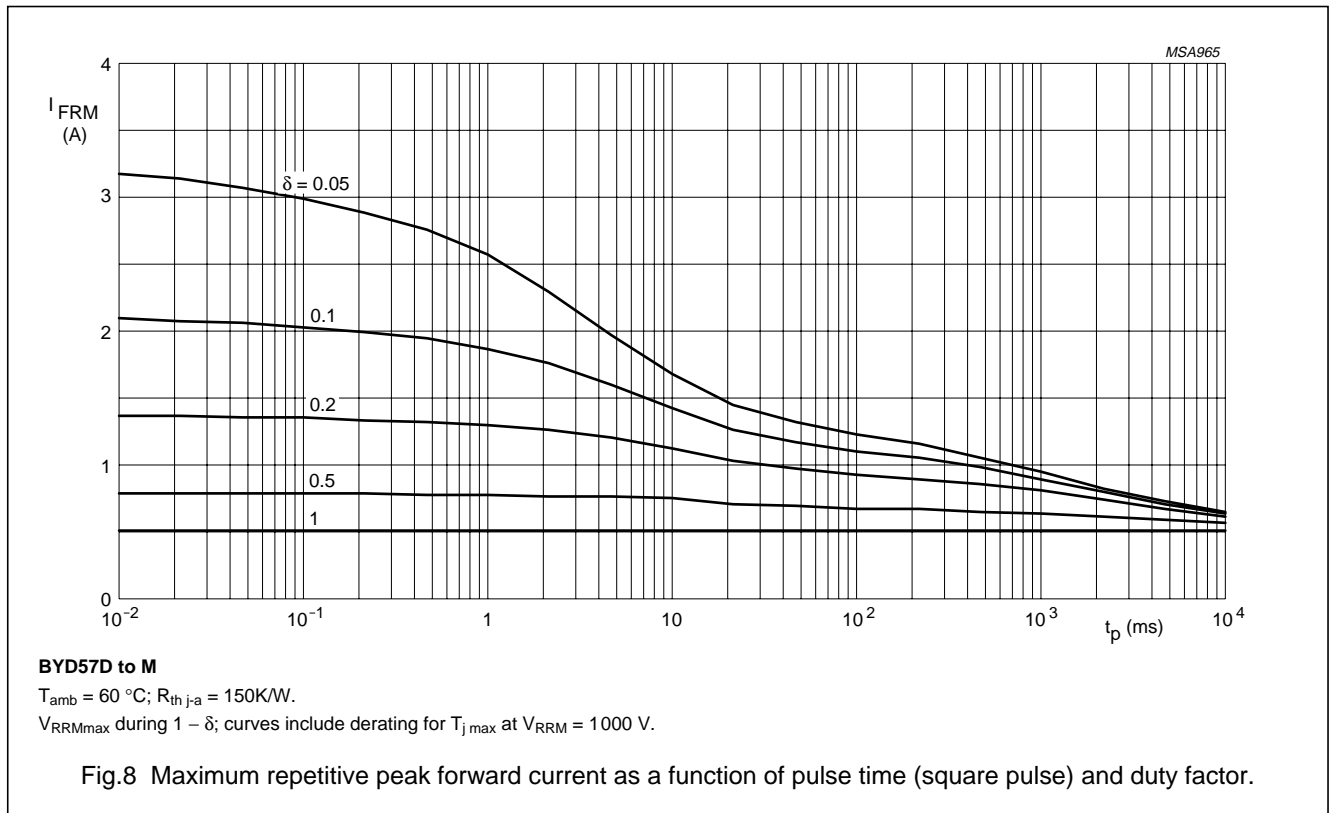
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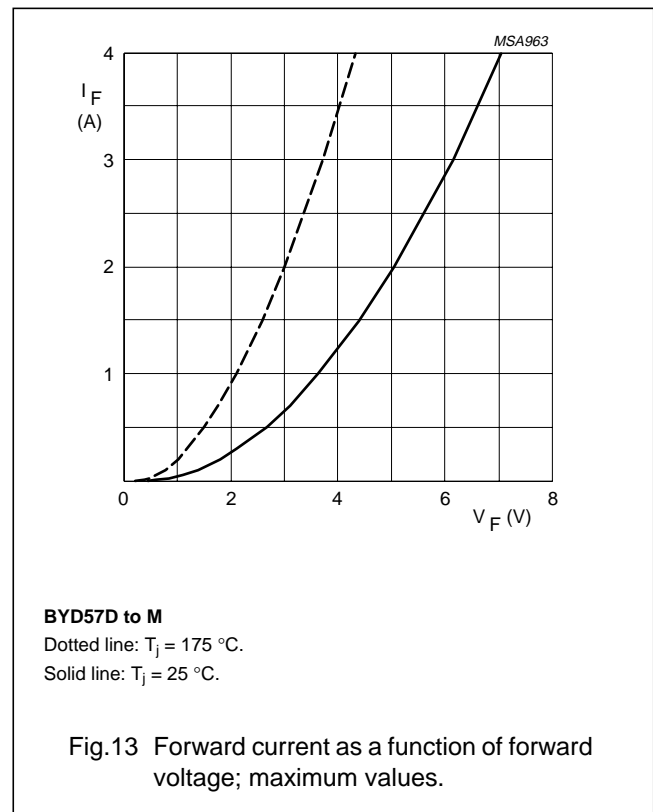
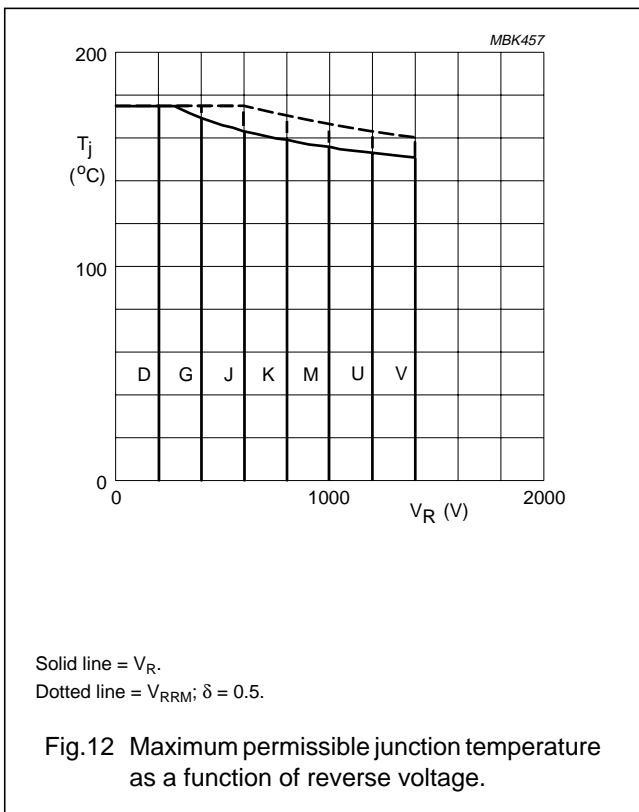
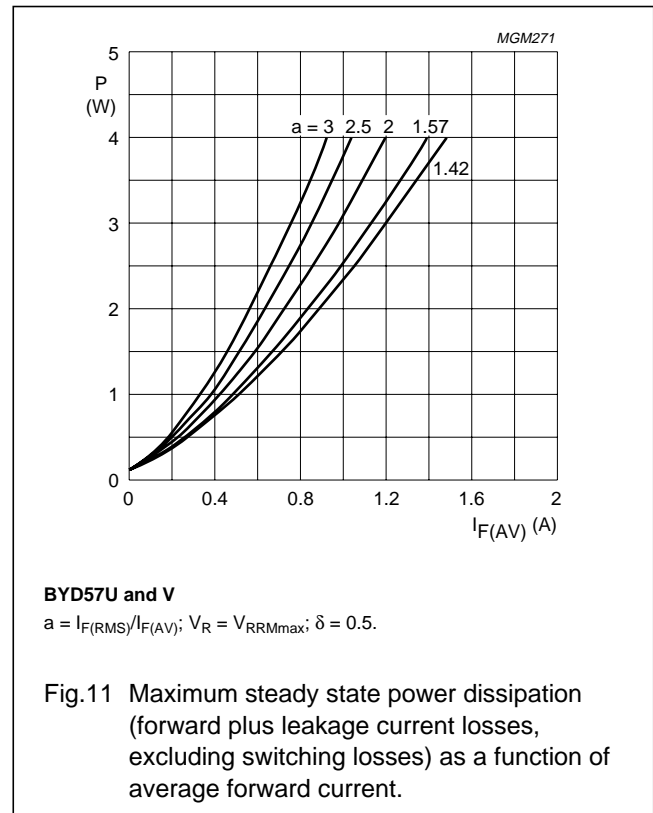
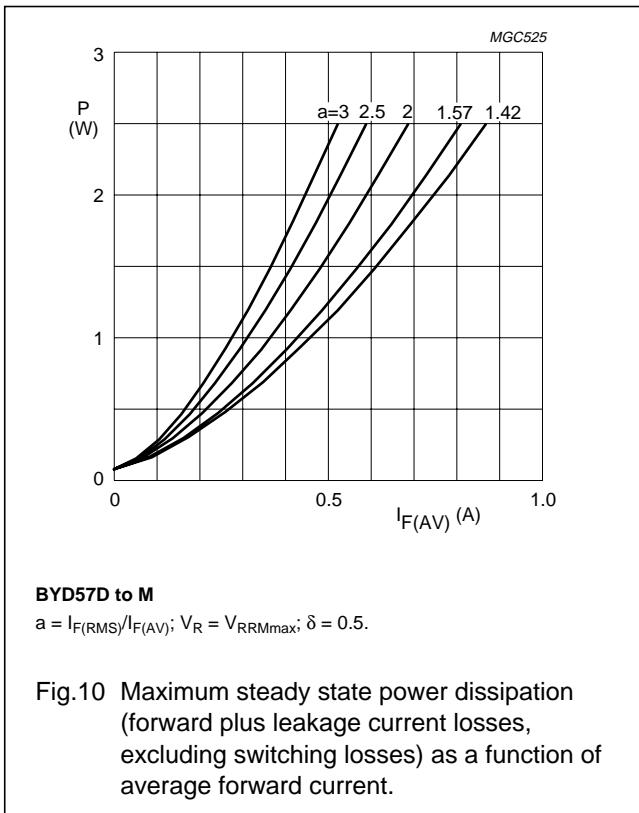
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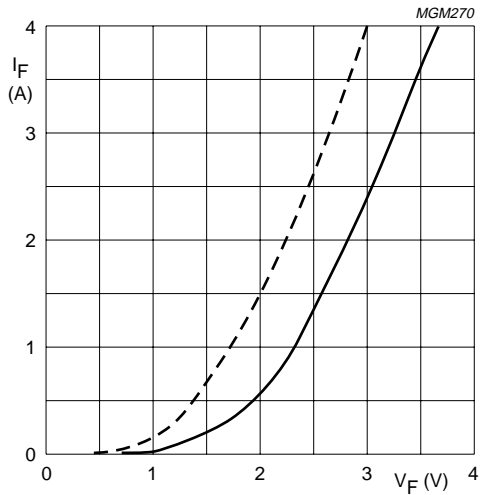
BYD57 series





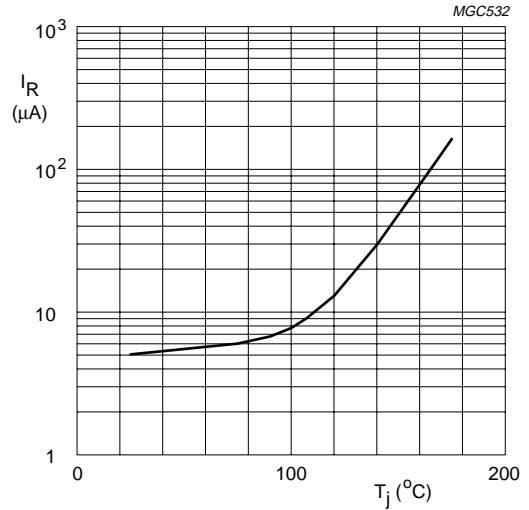
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BYD57 series



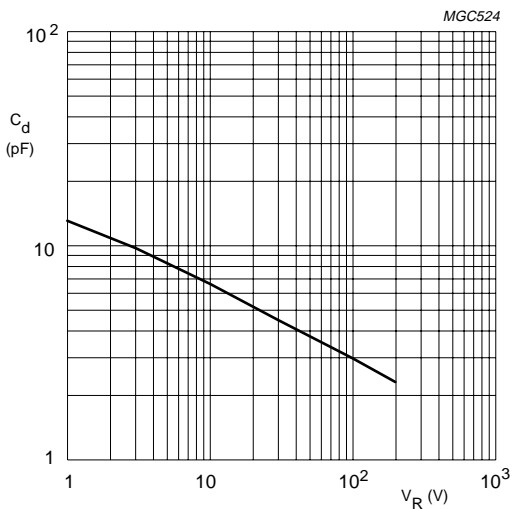
**BYD57U and V**  
Dotted line:  $T_j = 175\text{ }^\circ\text{C}$ .  
Solid line:  $T_j = 25\text{ }^\circ\text{C}$ .

Fig.14 Forward current as a function of forward voltage; maximum values.



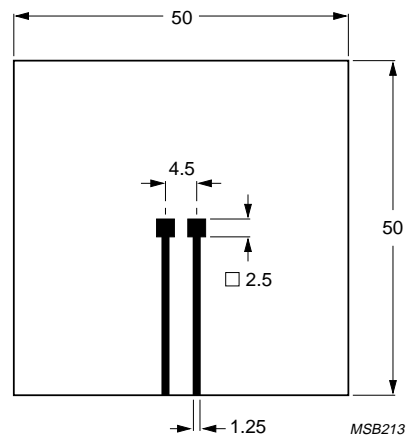
$V_R = V_{RRMmax}$ .

Fig.15 Reverse current as a function of junction temperature; maximum values.



$f = 1\text{ MHz}$ ;  $T_j = 25\text{ }^\circ\text{C}$ .

Fig.16 Diode capacitance as a function of reverse voltage; typical values.

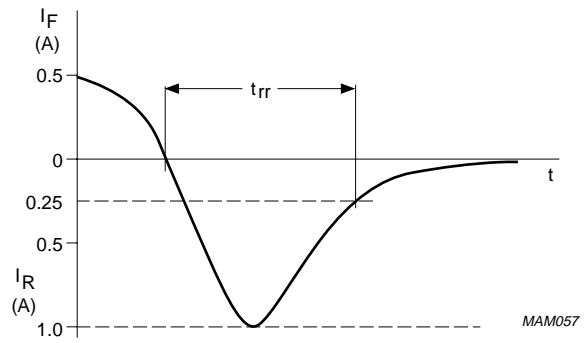
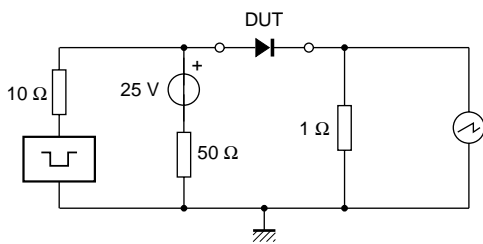


Dimensions in mm.

Fig.17 Printed-circuit board for surface mounting.

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controlled avalanche rectifiers

BYD57 series



Input impedance oscilloscope: 1 MΩ, 22 pF;  $t_r \leq 7$  ns.  
Source impedance: 50 Ω;  $t_r \leq 15$  ns.

Fig.18 Test circuit and reverse recovery time waveform and definition.

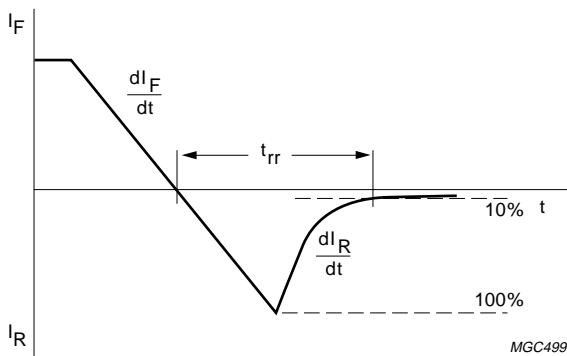


Fig.19 Reverse recovery definitions.

Ultra-fast soft-recovery  
controlled avalanche rectifiers

BYD57 series

PACKAGE OUTLINE

Hermetically sealed glass surface mounted package;  
Implotec™(1) technology; 2 connectors

SOD87

**DIMENSIONS (mm are the original dimensions)**

UNIT	D	D1	H	L
mm	2.1 2.0	2.0 1.8	3.7 3.3	0.3

**Notes**

- Implotec is a trademark of Philips.
- The marking indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD87	100H03					99-03-31 99-06-04

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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# Philips Semiconductors – a worldwide company

**Argentina:** see South America

**Australia:** 3 Figtree Drive, HOME BUSH, NSW 2140,  
Tel. +61 2 9704 8141, Fax. +61 2 9704 8139

**Austria:** Computerstr. 6, A-1101 WIEN, P.O. Box 213,  
Tel. +43 1 60 101 1248, Fax. +43 1 60 101 1210

**Belarus:** Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,  
220050 MINSK, Tel. +375 172 20 0733, Fax. +375 172 20 0773

**Belgium:** see The Netherlands

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**Bulgaria:** Philips Bulgaria Ltd., Energoproject, 15th floor,  
51 James Bourchier Blvd., 1407 SOFIA,  
Tel. +359 2 68 9211, Fax. +359 2 68 9102

**Canada:** PHILIPS SEMICONDUCTORS/COMPONENTS,  
Tel. +1 800 234 7381, Fax. +1 800 943 0087

**China/Hong Kong:** 501 Hong Kong Industrial Technology Centre,  
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,  
Tel. +852 2319 7888, Fax. +852 2319 7700

**Colombia:** see South America

**Czech Republic:** see Austria

**Denmark:** Sydhavnsgade 23, 1780 COPENHAGEN V,  
Tel. +45 33 29 3333, Fax. +45 33 29 3905

**Finland:** Sinikalliontie 3, FIN-02630 ESPOO,  
Tel. +358 9 615 800, Fax. +358 9 6158 0920

**France:** 51 Rue Carnot, BP317, 92156 SURESNES Cedex,  
Tel. +33 1 4099 6161, Fax. +33 1 4099 6427

**Germany:** Hammerbrookstraße 69, D-20097 HAMBURG,  
Tel. +49 40 2353 60, Fax. +49 40 2353 6300

**Hungary:** see Austria

**India:** Philips INDIA Ltd, Band Box Building, 2nd floor,  
254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,  
Tel. +91 22 493 8541, Fax. +91 22 493 0966

**Indonesia:** PT Philips Development Corporation, Semiconductors Division,  
Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510,  
Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

**Ireland:** Newstead, Clonskeagh, DUBLIN 14,  
Tel. +353 1 7640 000, Fax. +353 1 7640 200

**Israel:** RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,  
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

**Italy:** PHILIPS SEMICONDUCTORS, Via Casati, 23 - 20052 MONZA (MI),  
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**Japan:** Philips Bldg 13-37, Kohnan 2-chome, Minato-ku,  
TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5057

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**Malaysia:** No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,  
Tel. +60 3 750 5214, Fax. +60 3 757 4880

**Mexico:** 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,  
Tel. +9-5 800 234 7381, Fax +9-5 800 943 0087

**Middle East:** see Italy

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Tel. +31 40 27 82785, Fax. +31 40 27 88399

**New Zealand:** 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,  
Tel. +64 9 849 4160, Fax. +64 9 849 7811

**Norway:** Box 1, Manglerud 0612, OSLO,  
Tel. +47 22 74 8000, Fax. +47 22 74 8341

**Pakistan:** see Singapore

**Philippines:** Philips Semiconductors Philippines Inc.,  
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,  
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

**Poland:** Al.Jerozolimskie 195 B, 02-222 WARSAW,  
Tel. +48 22 5710 000, Fax. +48 22 5710 001

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Tel. +27 11 471 5401, Fax. +27 11 471 5398

**South America:** Al. Vicente Pinzon, 173, 6th floor,  
04547-130 SÃO PAULO, SP, Brazil,  
Tel. +55 11 821 2333, Fax. +55 11 821 2382

**Spain:** Balmes 22, 08007 BARCELONA,  
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**Sweden:** Kottbygatan 7, Akalla, S-16485 STOCKHOLM,  
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TAIPEI, Taiwan Tel. +886 2 2134 2886, Fax. +886 2 2134 2874

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209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,  
Tel. +66 2 745 4090, Fax. +66 2 398 0793

**Turkey:** Yukari Dudullu, Org. San. Blg., 2.Cad. Nr. 28 81260 Umraniye,  
ISTANBUL, Tel. +90 216 522 1500, Fax. +90 216 522 1813

**Ukraine:** PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,  
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

**United Kingdom:** Philips Semiconductors Ltd., 276 Bath Road, Hayes,  
MIDDLESEX UB3 5BX, Tel. +44 208 730 5000, Fax. +44 208 754 8421

**United States:** 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,  
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